

Amendments to the Specification

Please replace the original title on page 1, lines 2-3, with the following replacement title:

SEMICONDUCTOR DEVICE ~~AND METHOD OF MANUFACTURING SAME~~ HAVING AN INTERLAYER DIELECTRIC FORMED ON A TRANSISTOR THEREOF

Please insert prior to pre-numbered line 5 on page 1, the following text:

CROSS REFERENCE TO RELATED APPLICATIONS

This application is a divisional of application no. 09/778,104, filed February 7, 2001, now U.S. Patent No. 6,787,855.